Malgorzata Kot

List of Publications by Year in descending order

Source: https://exaly.com/author-pdf/1038688/publications.pdf Version: 2024-02-01



| # | Article | IF | CITATIONS |
|----|---|-----|-----------|
| 1 | Roomâ€Temperature Atomic Layer Deposition of Al ₂ O ₃ : Impact on Efficiency, Stability and Surface Properties in Perovskite Solar Cells. ChemSusChem, 2016, 9, 3401-3406. | 6.8 | 76 |
| 2 | Understanding the growth mechanism of graphene on Ge/Si(001) surfaces. Scientific Reports, 2016, 6, 31639. | 3.3 | 44 |
| 3 | Roomâ€Temperature Atomic‣ayerâ€Deposited Al ₂ O ₃ Improves the Efficiency of Perovskite Solar Cells over Time. ChemSusChem, 2018, 11, 3640-3648. | 6.8 | 33 |
| 4 | Tailoring optical and electrical properties of thin-film coatings based on mixed Hf and Ti oxides for optoelectronic application. Materials and Design, 2019, 175, 107822. | 7.0 | 25 |
| 5 | Localized defect states and charge trapping in atomic layer deposited-Al2O3 films. Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films, 2017, 35, . | 2.1 | 24 |
| 6 | Evidence of Nitrogen Contribution to the Electronic Structure of the CH ₃ NH ₃ PbI ₃ Perovskite. Chemistry - A European Journal, 2018, 24, 3539-3544. | 3.3 | 20 |
| 7 | Atomic Layer-Deposited Aluminum Oxide Hinders lodide Migration and Stabilizes Perovskite Solar Cells. Cell Reports Physical Science, 2020, 1, 100112. | 5.6 | 20 |
| 8 | Analysis of nitrogen species in titanium oxynitride ALD films. Applied Surface Science, 2016, 381, 42-47. | 6.1 | 19 |
| 9 | Analysis of titanium species in titanium oxynitride films prepared by plasma enhanced atomic layer deposition. Surface and Coatings Technology, 2017, 324, 586-593. | 4.8 | 17 |
| 10 | Engineering of Subâ€Nanometer SiO _{<i>x</i>} Thickness in Si Photocathodes for Optimized Open Circuit Potential. ChemSusChem, 2016, 9, 2332-2336. | 6.8 | 16 |
| 11 | In situ Nearâ€Ambient Pressure Xâ€ray Photoelectron Spectroscopy Reveals the Influence of Photon Flux and Water on the Stability of Halide Perovskite. ChemSusChem, 2020, 13, 5722-5730. | 6.8 | 15 |
| 12 | In-gap states in titanium dioxide and oxynitride atomic layer deposited films. Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films, 2017, 35, . | 2.1 | 14 |
| 13 | Room temperature atomic layer deposited Al2O3 on CH3NH3PbI3 characterized by synchrotron-based X-ray photoelectron spectroscopy. Nuclear Instruments & Methods in Physics Research B, 2017, 411, 49-52. | 1.4 | 13 |
| 14 | Thermal stability of CH3NH3PbIxCl3-x versus [HC(NH2)2]0.83Cs0.17PbI2.7Br0.3 perovskite films by X-ray photoelectron spectroscopy. Applied Surface Science, 2020, 513, 145596. | 6.1 | 13 |
| 15 | Long-term ambient surface oxidation of titanium oxynitride films prepared by plasma-enhanced atomic layer deposition: An XPS study. Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films, 2018, 36, . | 2.1 | 9 |
| 16 | Al 2 O 3 â€Atomic Layer Deposited Films on CH 3 NH 3 PbI 3 : Intrinsic Defects and Passivation Mechanisms. Energy Technology, 2019, 7, 1900975. | 3.8 | 8 |
| 17 | Comparison of plasma-enhanced atomic layer deposition AlN films prepared with different plasma sources. Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films, 2019, 37, . | 2.1 | 8 |
| | | | |

An (In Situ)2 Approach: ALD and resPES Applied to Al2O3, HfO2, and TiO2 Ultrathin Films. , 2018, , 18-26.

7

Malgorzata Kot

| # | Article | IF | CITATIONS |
|----|---|-----|-----------|
| 19 | Point Defect-Mediated Interface Formation and Appearance of a Cooper Minimum for AlO <i>_x</i> Atomic-Layer-Deposited Films on CH ₃ NH ₃ Pbl ₃ . Journal of Physical Chemistry C, 2019, 123, 23352-23360. | 3.1 | 7 |
| 20 | Topâ€Down Approach to Study Chemical and Electronic Properties of Perovskite Solar Cells: Sputtered Depth Profiling Versus Tapered Cross‧ectional Photoelectron Spectroscopies. Solar Rrl, 2021, 5, 2100298. | 5.8 | 6 |
| 21 | Band Bending at Hole Transporting Layerâ€Perovskite Interfaces in nâ€iâ€p and in pâ€iâ€n Architecture. Solar Rrl, 2022, 6, . | 5.8 | 6 |
| 22 | Selective Deposition of an Ultrathin Pt Layer on a Au-Nanoisland-Modified Si Photocathode for Hydrogen Generation. ACS Omega, 2017, 2, 1360-1366. | 3.5 | 5 |
| 23 | Interface Potentials, Intrinsic Defects, and Passivation Mechanisms in Al2O3, HfO2, and TiO2 Ultrathin Films. , 2018, , 162-171. | | 4 |
| 24 | Toward controlling the Al ₂ O ₃ /ZnO interface properties by <i>in situ</i> ALD preparation. Dalton Transactions, 2022, 51, 9291-9301. | 3.3 | 4 |
| 25 | Analysis of surface properties of Ti-Cu-Ox gradient thin films using AFM and XPS investigations. Materials Science-Poland, 2018, 36, 761-768. | 1.0 | 3 |
| 26 | Low-temperature atomic layer deposition of indium oxide thin films using trimethylindium and oxygen plasma. Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films, 2021, 39, 062406. | 2.1 | 3 |
| 27 | Themed issue on electronic properties and characterisation of perovskites. Journal of Materials Chemistry C, 2019, 7, 5224-5225. | 5.5 | 1 |
| 28 | Self-Assembled Monolayers from Symmetrical Di-Thiols: Preparation, Characterization and Application for the Assembly of Electrochemically Active Films. Engineering Proceedings, 2021, 6, . | 0.4 | 0 |